TOSHIBA

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π -MOSVII)

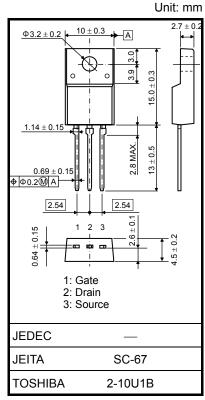
TK6A53D

Switching Regulator Applications

- Low drain-source ON-resistance: RDS (ON) = 1.1Ω (typ.)
- High forward transfer admittance: $|Y_{fs}| = 2.5 \text{ S}$ (typ.)
- Low leakage current: $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 525 \ V)$
- Enhancement mode: $V_{th} = 2.4$ to 4.4 V ($V_{DS} = 10$ V, $I_D = 1$ mA)

Characte	ristics	Symbol	Rating	Unit				
Drain-source voltage		V _{DSS}	525	V				
Gate-source voltage		V _{GSS}	±30	V				
Drain current	DC (Note 1)	۱ _D	6					
	Pulse (t = 1 ms) (Note 1)	I _{DP}	24	A				
Drain power dissipati	on (Tc = 25°C)	PD	35	W				
Single pulse avalancl	ne energy (Note 2)	E _{AS}	147	mJ				
Avalanche current		I _{AR}	6	А				
Repetitive avalanche	energy (Note 3)	E _{AR}	3.5	mJ				
Channel temperature		T _{ch}	150	°C				
Storage temperature	range	T _{stg}	-55 to 150	°C				

Absolute Maximum Ratings (Ta = 25°C)



Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

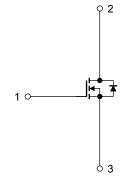
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	3.57	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	62.5	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: $V_{DD} = 90 \text{ V}, \text{ T}_{ch} = 25^{\circ}\text{C}(\text{initial}), \text{ L} = 7.02 \text{ mH}, \text{ R}_{G} = 25 \Omega, \text{ I}_{AR} = 6 \text{ A}$

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Handle with care.



Start of commercial production 2009-02

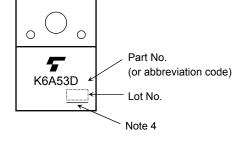
Electrical Characteristics (Ta = 25°C)

Char	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS}=\pm 30~V,~V_{DS}=0~V$	_		±1	μA
Drain cut-off current		I _{DSS}	$V_{DS} = 525 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			10	μA
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	525			V
Gate threshold v	oltage	V _{th}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	2.4		4.4	V
Drain-source ON	-resistance	R _{DS (ON)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 3 \text{ A}$	_	1.1	1.3	Ω
Forward transfer	admittance	Y _{fs}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 3 \text{ A}$	0.7	2.5	_	S
Input capacitance		C _{iss}		_	600	_	
Reverse transfer capacitance		C _{rss}	V_{DS} = 25 V, V_{GS} = 0 V, f = 1 MHz	_	4	_	pF
Output capacitance		C _{oss}			70		
Switching time	Rise time	tr	V_{GS} $0 V$ V_{GS} $0 V$		18	_	- ns
	Turn-on time	t _{on}			40		
	Fall time	t _f			8	_	
	Turn-off time	t _{off}	$v_{DD} \approx 200 v$ Duty $\leq 1\%$, t _W = 10 µs	_	55	—	
Total gate charge		Qg			12		
Gate-source charge		Q _{gs}	$V_{DD}\approx 400$ V, $V_{GS}=10$ V, $I_{D}=6$ A		7		nC
Gate-drain charge		Q _{gd}]	_	5	_	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	—	_	_	6	А
Pulse drain reverse current (Note 1)	I _{DRP}	—	_	_	24	А
Forward voltage (diode)	V _{DSF}	$I_{DR} = 6 \text{ A}, V_{GS} = 0 \text{ V}$	_	_	-1.7	V
Reverse recovery time	t _{rr}	$I_{DR} = 6 \text{ A}, V_{GS} = 0 \text{ V},$	_	1200	_	ns
Reverse recovery charge	Qrr	dl _{DR} /dt = 100 A/μs	_	7	_	μC

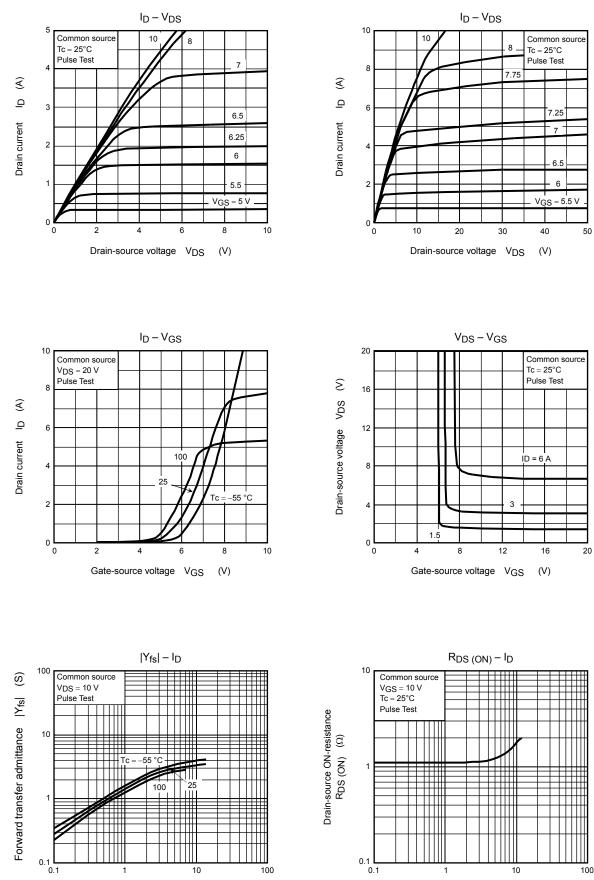
Marking



Note 4: A line under a Lot No. identifies the indication of product Labels [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

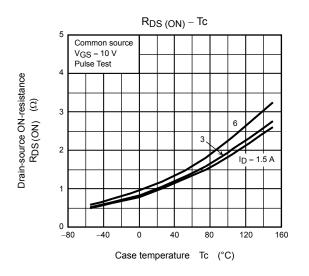
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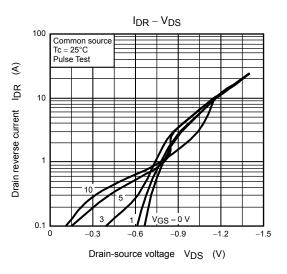


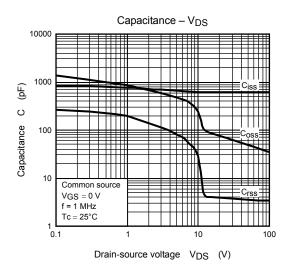
Drain current ID (A)

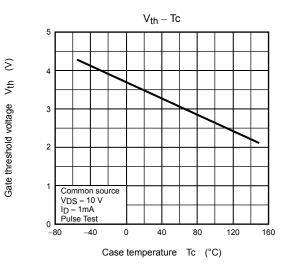
Drain current ID (A)

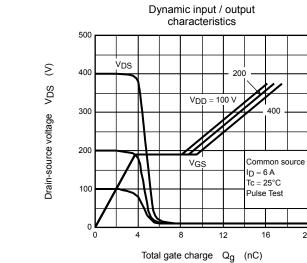
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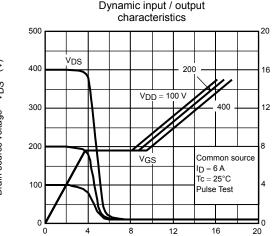








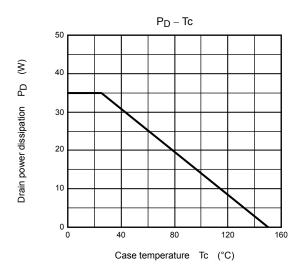




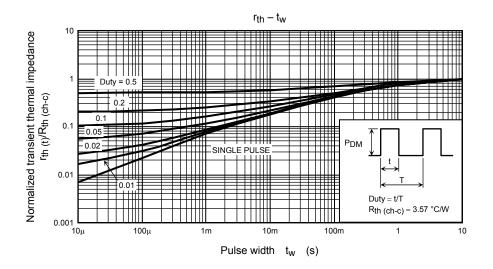
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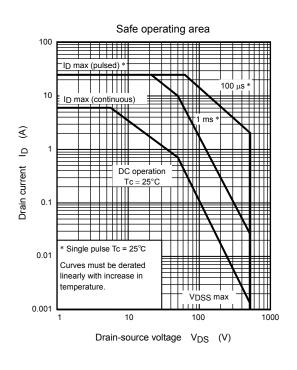
VGS

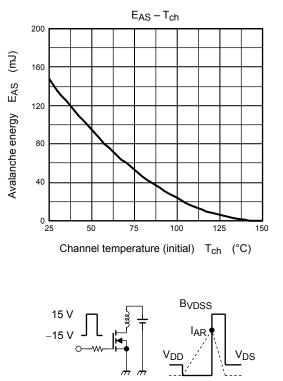
Gate-source voltage

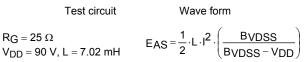


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